Felix CÃ¹/₄ppers

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/3333988/publications.pdf

Version: 2024-02-01

1307594 1720034 9 438 7 7 citations g-index h-index papers 9 9 9 478 citing authors docs citations times ranked all docs

#	Article	IF	CITATIONS
1	Improved Switching Stability and the Effect of an Internal Series Resistor in HfO ₂ /TiO _{<italic>x</italic>} Bilayer ReRAM Cells. IEEE Transactions on Electron Devices, 2018, 65, 3229-3236.	3.0	95
2	Exploiting the switching dynamics of HfO2-based ReRAM devices for reliable analog memristive behavior. APL Materials, $2019, 7, .$	5.1	94
3	Variability-Aware Modeling of Filamentary Oxide-Based Bipolar Resistive Switching Cells Using SPICE Level Compact Models. IEEE Transactions on Circuits and Systems I: Regular Papers, 2020, 67, 4618-4630.	5.4	72
4	Understanding the Coexistence of Two Bipolar Resistive Switching Modes with Opposite Polarity in Pt/TiO ₂ /Ti/Pt Nanosized ReRAM Devices. ACS Applied Materials & Interfaces, 2018, 10, 29766-29778.	8.0	71
5	Design of defect-chemical properties and device performance in memristive systems. Science Advances, 2020, 6, eaaz9079.	10.3	65
6	Utilizing the Switching Stochasticity of HfO2/TiOx-Based ReRAM Devices and the Concept of Multiple Device Synapses for the Classification of Overlapping and Noisy Patterns. Frontiers in Neuroscience, 2021, 15, 661856.	2.8	26
7	Intrinsic RESET Speed Limit of Valence Change Memories. ACS Applied Electronic Materials, 2021, 3, 5563-5572.	4.3	15
8	Reliability Aspects of Memristive Devices for Computation-in-Memory Applications., 2021,,.		0
9	NEUROTEC I: Neuro-inspired Artificial Intelligence Technologies for the Electronics of the Future. , 2022, , .		O